



v04.0210

SMT GaAs HBT MMIC x8 ACTIVE FREQUENCY MULTIPLIER, 9.9 - 11.2 GHz OUTPUT

Typical Applications

Active Multiplier for X Band Applications:

- Fiber Optic
- Point-to-Point Radios
- Military Radar

Functional Diagram

N/C Vcc \geq Z \geq 22 24 21 20 19 23 N/C 18 N/C 1 17 N/C N/C 2 16 RFOUT RFIN 3 Χ8 GND 4 15 GND N/C N/C 5 14 N/C N/C 6 13 7 8 9 10 11 12 PACKAGE N/C N/C V/C N/C N/C N/C BASE GND TOP VIEW

Features

Output Power: +6 dBm Sub-Harmonic Suppression: >25 dBc SSB Phase Noise: -136 dBc/Hz Single Supply: +5V@ 68 mA 24 Lead 4x4 mm SMT Package: 16 mm²

General Description

The HMC444LP4 & HMC444LP4E are active miniature x8 frequency multipliers utilizing InGaP GaAs HBT technology in 4x4 mm leadless surface mount packages. Power output is +6 dBm typical from a 5V supply voltage and varies little vs. input power, temperature and supply voltage. Suppression of undesired fundamental and sub-harmonics is >25 dBc typical with respect to output signal level. The low additive SSB phase noise of -136 dBc/Hz at 100 kHz offset helps the user maintain good system noise performance. The HMC444LP4 & HMC444LP4E are ideal for use in LO multiplier chains allowing reduced parts count vs. traditional approaches.

Electrical Specifications, $T_{a} = +25^{\circ} C$, Vcc= 5V

Parameter	Min.	Тур.	Max.	Units
Frequency Range, Input	1.2375 - 1.40		GHz	
Frequency Range, Output	9.9 - 11.2		GHz	
Input Power Range	-15		+5	dBm
Output Power	3	6		dBm
Sub-Harmonic Suppression		25		dBc
Input Return Loss		22		dB
Output Return Loss		7		dB
SSB Phase Noise (100 kHz Offset) Pin= 0 dBm		-136		dBc/Hz
Supply Current (Icc)		68	91	mA

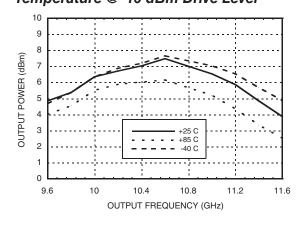
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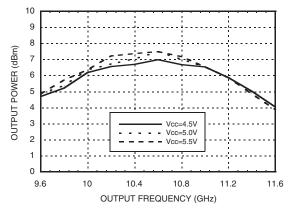


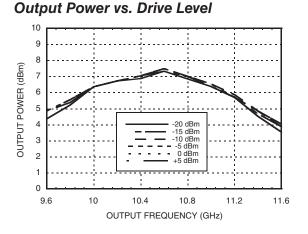
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Output Power vs. Temperature @ -10 dBm Drive Level

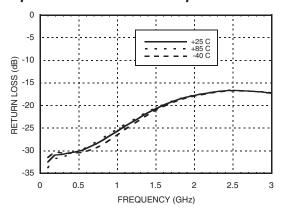


Output Power vs. Supply Voltage @ -10 dBm Drive Level

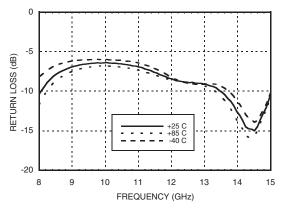




Input Return Loss vs. Temperature



Output Return Loss vs. Temperature



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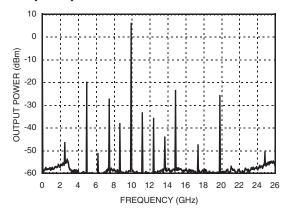




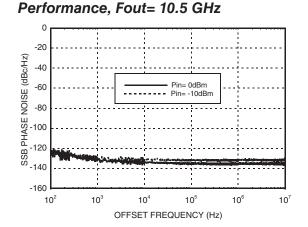
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SSB Phase Noise

Output Spectrum



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Absolute Maximum Ratings

RF Input (Vcc = +5V)	+20 dBm
Vcc	+5.5V
Channel Temperature	135 °C
Continuous Pdiss (T=85 °C) (derate 10 mW/°C above 85 °C)	650 mW
Thermal Resistance (R _{th}) (junction to ground paddle)	100 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vcc

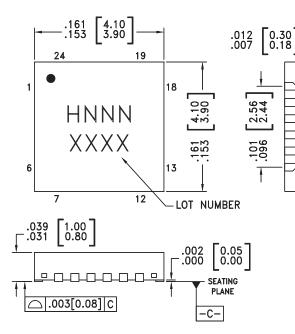
Vcc (V)	Icc (mA)
4.5	66
5.0	68
5.5	70

Note: Multiplier will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE **OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



BOTTOM VIEW

PIN 24 -.016 [0.40] REF .008 [0.20] MIN $\Box \sqcup \Box$ PIN 1 0.56 .022 2.95 2.65 .116 04 RF/DC GROUND SQUARE

EXPOSED GROUND PADDLE MUST BE CONNECTED TO

NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

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Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC444LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H444 XXXX
HMC444LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H444 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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Pin Description

Pin Number	Function	Description	Interface Schematic
1, 2, 5 - 14, 17, 18, 20 - 24	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	RFIN	RF input needs to be DC blocked only if there is an external DC voltage applied to RF IN.	RFIN ○
4, 15	GND	All ground leads and ground paddle must be soldered to PCB RF/DC ground.	
16	RFOUT	Multiplied Output. AC coupled. No external DC blocks necessary.	
19	Vcc	Supply voltage 5V \pm 0.5V.	

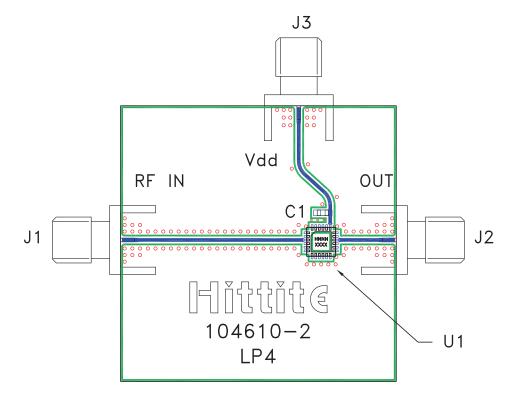


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Evaluation PCB



List of Materials for Evaluation PCB 106137 [1]

Item	Description	
J1 - J3	PCB Mount SMA Connector	
C1	1,000 pF Capacitor, 0603 Pkg.	
U1	HMC444LP4(E) x8 Active Multiplier	
PCB [2]	104610 Eval Board	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. The evaluation circuit board shown is available from Hittite upon request.